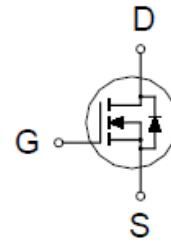
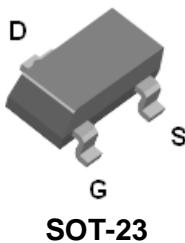


# PA606BMG

## N-Channel Enhancement Mode MOSFET

### PRODUCT SUMMARY

$V_{(BR)DSS}$	$R_{DS(ON)}$	$I_D$
55V	180m $\Omega$ @ $V_{GS} = 10V$	1.6A



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		$V_{DS}$	55	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	
Continuous Drain Current	$T_A = 25^\circ C$	$I_D$	1.6	A
	$T_A = 70^\circ C$		1	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	11	
Avalanche Current		$I_{AS}$	11	
Avalanche Energy	$L = 0.1mH$	$E_{AS}$	6	mJ
Power Dissipation	$T_A = 25^\circ C$	$P_D$	0.8	W
	$T_A = 70^\circ C$		0.3	
Operating Junction & Storage Temperature Range		$T_J, T_{STG}$	-55 to 150	°C

### THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Ambient	$R_{\theta JA}$		140	°C / W

<sup>1</sup>Pulse width limited by maximum junction temperature.

# PA606BMG

## N-Channel Enhancement Mode MOSFET

### ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = 250\mu\text{A}$	55			V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = 250\mu\text{A}$	1.0	1.5	2.5	
Gate-Body Leakage	$I_{\text{GSS}}$	$V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = \pm 20\text{V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}} = 44\text{V}, V_{\text{GS}} = 0\text{V}$			1	$\mu\text{A}$
		$V_{\text{DS}} = 40\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 55^\circ\text{C}$			10	
On-State Drain Current <sup>1</sup>	$I_{\text{D}(\text{ON})}$	$V_{\text{DS}} = 5\text{V}, V_{\text{GS}} = 10\text{V}$	11			A
Drain-Source On-State Resistance <sup>1</sup>	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}} = 4.5\text{V}, I_D = 1.5\text{A}$		158	250	$\text{m}\Omega$
		$V_{\text{GS}} = 10\text{V}, I_D = 1.6\text{A}$		135	180	
Forward Transconductance <sup>1</sup>	$g_{\text{fs}}$	$V_{\text{DS}} = 5\text{V}, I_D = 1.6\text{A}$		6		S
<b>DYNAMIC</b>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = 25\text{V}, f = 1\text{MHz}$		243		pF
Output Capacitance	$C_{\text{oss}}$			18		
Reverse Transfer Capacitance	$C_{\text{rss}}$			14		
Gate Resistance	$R_g$	$V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = 0\text{V}, f = 1\text{MHz}$		2.3		$\Omega$
Total Gate Charge <sup>2</sup>	$Q_g$	$V_{\text{DS}} = 0.5\text{V}, V_{\text{GS}} = 10\text{V}, I_D = 1.6\text{A}$		6.4		nC
Gate-Source Charge <sup>2</sup>	$Q_{\text{gs}}$			0.8		
Gate-Drain Charge <sup>2</sup>	$Q_{\text{gd}}$			2.5		
Turn-On Delay Time <sup>2</sup>	$t_{\text{d}(\text{on})}$	$V_{\text{DS}} = 30\text{V}, I_D \geq 1.5\text{A}, V_{\text{GS}} = 10\text{V}, R_G = 1\Omega$		6		nS
Rise Time <sup>2</sup>	$t_r$			15		
Turn-Off Delay Time <sup>2</sup>	$t_{\text{d}(\text{off})}$			15		
Fall Time <sup>2</sup>	$t_f$			10		
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (<math>T_J = 25^\circ\text{C}</math>)</b>						
Continuous Current	$I_S$				1.6	A
Forward Voltage <sup>1</sup>	$V_{\text{SD}}$	$I_F = 1.6\text{A}, V_{\text{GS}} = 0\text{V}$			1.2	V
Reverse Recovery Time	$t_{\text{rr}}$	$I_F = 1.6\text{A}, dI/dt = 100\text{A}/\mu\text{s}$		18.3		nS
Reverse Recovery Charge	$Q_{\text{rr}}$			13		nC

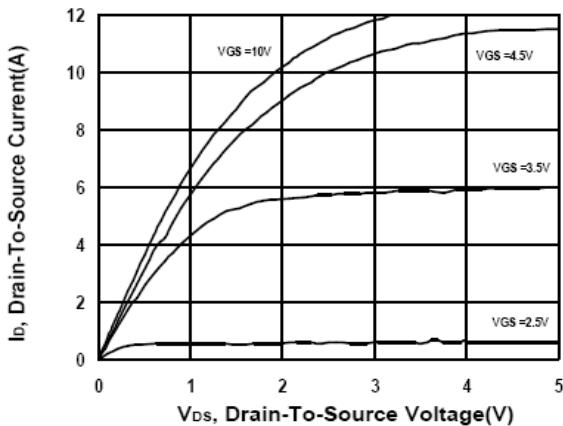
<sup>1</sup>Pulse test : Pulse Width  $\leq 300\ \mu\text{sec}$ , Duty Cycle  $\leq 2\%$ .

<sup>2</sup>Independent of operating temperature.

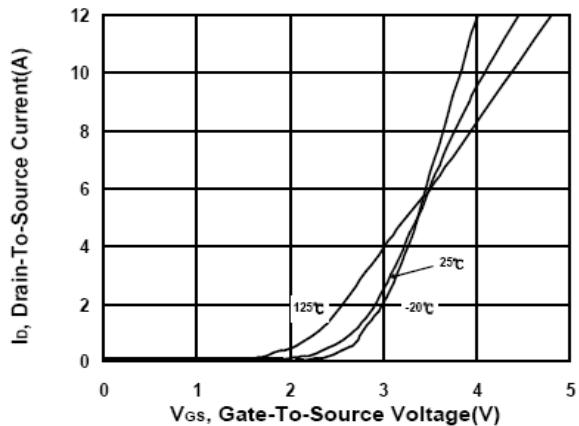
## PA606BMG

### N-Channel Enhancement Mode MOSFET

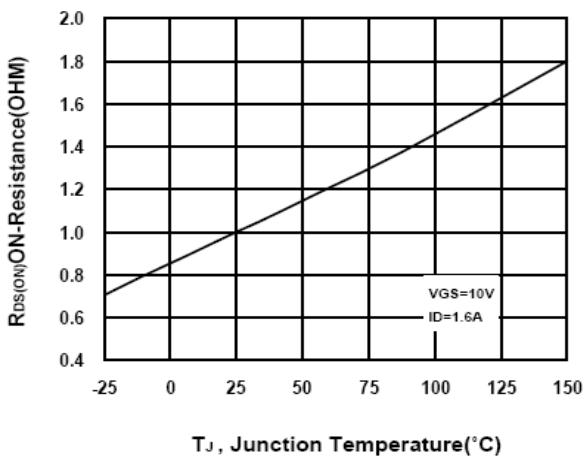
**Output Characteristics**



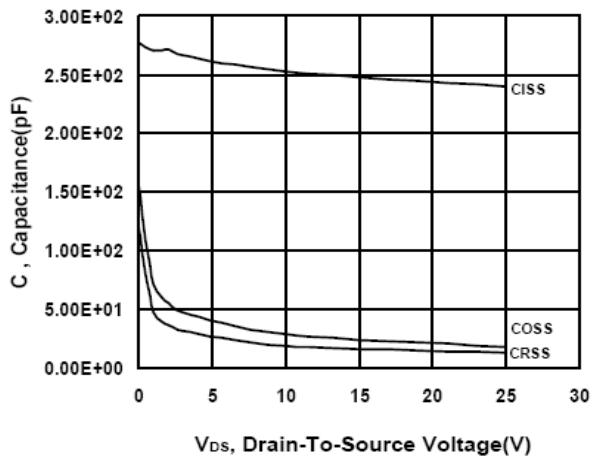
**Transfer Characteristics**



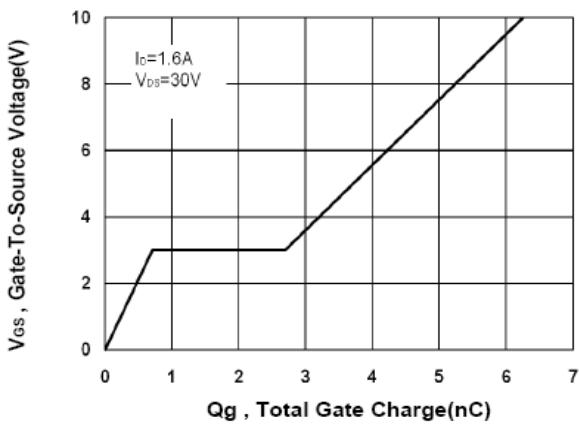
**On-Resistance VS Temperature**



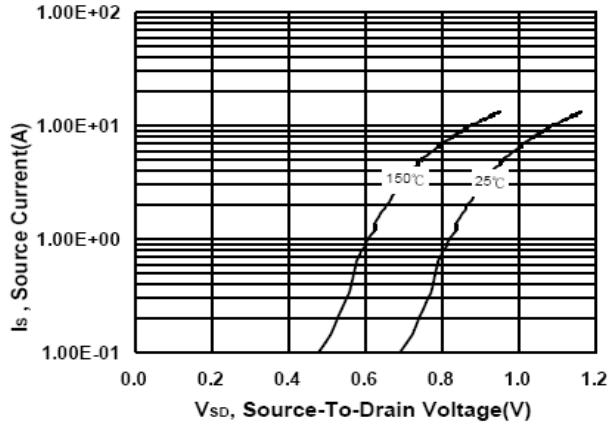
**Capacitance Characteristic**



**Gate charge Characteristics**

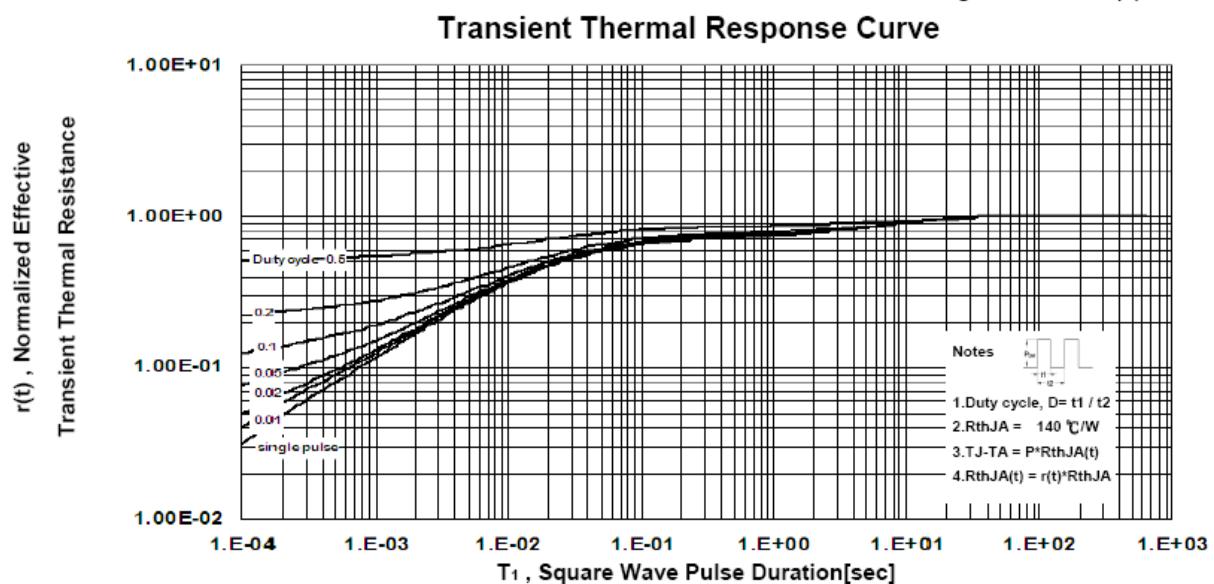
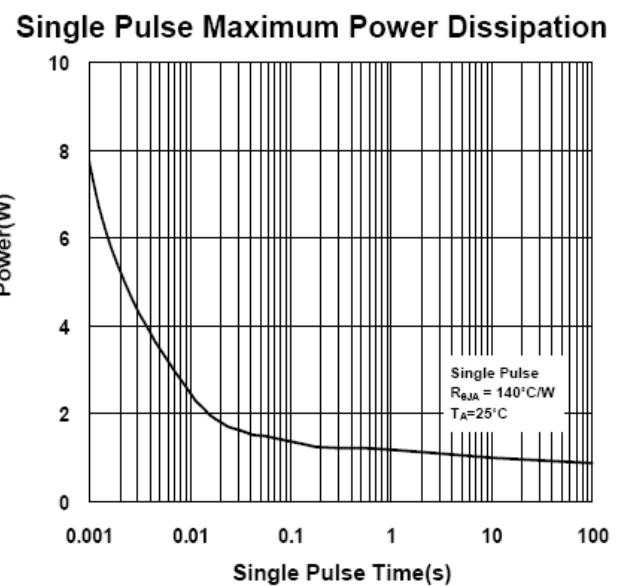
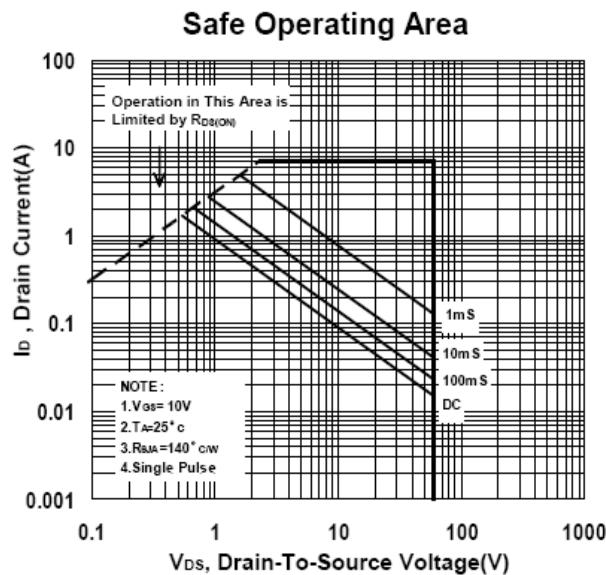


**Source-Drain Diode Forward Voltage**



## PA606BMG

### N-Channel Enhancement Mode MOSFET



# PA606BMG

## N-Channel Enhancement Mode MOSFET

### Package Dimension

#### SOT-23-3 MECHANICAL DATA

Dimension	mm			Dimension	mm		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A		1.05		H	0.1		0.2
B	2.4		3	I	0.3		0.6
C	1.4		1.73				
D	2.7		3.1				
E	1		1.31				
F	0		0.15				
G	0.3		0.5				

